## **Supporting Information**

## A Boron-decorated Melon-based Carbon Nitride as a Metalfree Photocatalyst for N<sub>2</sub> Fixation: a DFT Study

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Fig. S1 The top and side views of optimized structures of B-decorated melon-based CNs with (a)  $B_{int}$ , (b)  $B_N$ , and (c)  $B_C$  configurations.

**Table S1** Binding energy  $(E_b)$  and formation energies  $(E_{form})$  of B-decorated melonbased CNs with  $B_{int}$ ,  $B_N$  and  $B_C$ , in which  $B_{int}$  represents a B atom adsorption on melon-based CN, while the  $B_N$  and  $B_C$  are doping of single B atom to N and C atom respectively.

	B <sub>int1</sub>	B <sub>int3</sub>	B <sub>int4</sub>	B <sub>int5</sub>			
$E_{\rm b}({\rm eV})$	-1.93	-1.92	-3.42	-2.96			
	B <sub>N1</sub>	B <sub>N2</sub>	B <sub>N3</sub>	B <sub>N4</sub>	B <sub>N5</sub>	B <sub>N6</sub>	$B_{N7}$
$E_{\rm form} ({\rm eV})$	1.92	1.31	0.52	2.23	0.97	2.21	1.63
	B <sub>C1</sub>	B <sub>C2</sub>	B <sub>C3</sub>	B <sub>C4</sub>	B <sub>C5</sub>	B <sub>C6</sub>	
$E_{\rm form} ({\rm eV})$	1.62	0.96	0.70	0.74	0.83	1.04	



Fig. S2 Free energy diagrams for  $N_2$  reduction through distal, alternating and enzymatic mechanisms on the (a)  $B_{int5}$ , (b)  $B_{N3}$ , (c)  $B_{N5}$  and (d)  $B_{N2}$ .



Fig. S3 The various intermediates for  $N_2$  reduction through distal, alternating and enzymatic mechanisms on the (a)  $B_{int4}$ , (b)  $B_{int5}$ , (c)  $B_{N3}$ , (d)  $B_{N5}$  and (e)  $B_{N2}$ .



**Fig. S4** The charge difference density of adsorbed  $N_2$  on (a)  $B_{int4}$  through the end-on pattern, (b-c)  $B_{int5}$  through side-on and end-on patterns, (d)  $B_{N3}$  through the end-on pattern, (e-f)  $B_{N5}$  and (g-h)  $B_{N2}$  through the side-on and end-on patterns, respectively. The isosurface value is set to be 0.005 e/Å<sup>3</sup>. The orange and cyan regions represent charge accumulation and depletion, respectively.



Fig. S5 Free energy diagrams of HER on  $B_{int4}$ ,  $B_{int5}$ ,  $B_{N3}$ ,  $B_{N5}$  and  $B_{N2}$ .



Fig. S6 The computed band structures of (a) pure melon-based CN and (b)  $B_{int4}$ . The Fermi level is set as zero in dotted lines.



Fig. S7 (a) Variations of energy against the time for AIMD simulation of  $B_{int4}$ ; the simulation is run under 300 K for 20 ps with a time step of 0.5 fs. (b) The structure of  $B_{int4}$  in the dynamic simulation process at about 11, 13 and 20 ps.